## NSN 5961-01-154-0779

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View Online at https://aerobasegroup.com/nsn/5961-01-154-0779 **Inclosure Material:** Metal **Overall Length:** 0.920 inches **Overall Height:** 0.200 inches **Overall Width:** 0.300 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1300.0 nonrepetitive peak reverse voltage and 1200.0 repetitive peak off-state voltage and 1200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 75.00 amperes forward current, total rms horsepower metric and 75.00 amperes forward current, average of standard range **Special Features:** Junction pattern arrangement: pnpnp **Terminal Type And Quantity:** 3 screw Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: